

February 1998

Features

- Buffered Inputs
- Typical $f_{MAX} = 50\text{MHz}$ at $V_{CC} = 5\text{V}$, $C_L = 15\text{pF}$, $T_A = 25^\circ\text{C}$
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: $N_{IL} = 30\%$, $N_{IH} = 30\%$ of V_{CC} at $V_{CC} = 5\text{V}$
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, $V_{IL} = 0.8\text{V}$ (Max), $V_{IH} = 2\text{V}$ (Min)
 - CMOS Input Compatibility, $I_L \leq 1\mu\text{A}$ at V_{OL} , V_{OH}

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CD74HC166E	-55 to 125	16 Ld PDIP	E16.3
CD74HCT166E	-55 to 125	16 Ld PDIP	E16.3
CD74HC166M	-55 to 125	16 Ld SOIC	M16.15
CD74HCT166M	-55 to 125	16 Ld SOIC	M16.15
CD54HC166W	-55 to 125	Wafer	

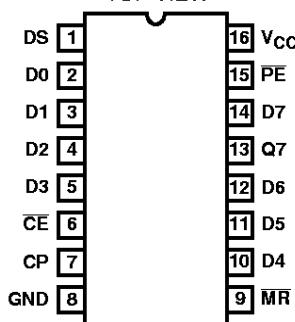
NOTES:

1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
2. Wafer and die is available which meets all electrical specifications. Please contact your local sales office or Harris customer service for ordering information.

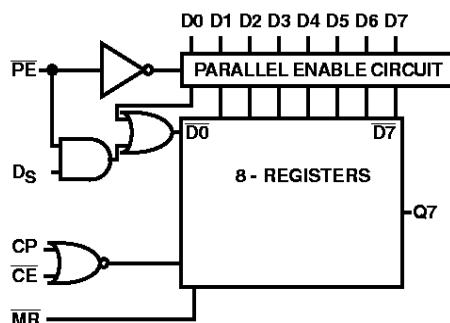
Pinout

CD74HC166, CD74HCT166 (PDIP, SOIC)

TOP VIEW



Functional Diagram



TRUTH TABLE

INPUTS						INTERNAL Q STATES		OUTPUT Q7	
MASTER RESET	PARALLEL ENABLE	CLOCK ENABLE	CLOCK	SERIAL	PARALLEL				
					D0	D7	Q0	Q1	
L	X	X	X	X	X	X	L	L	L
H	X	L	L	X	X	X	Q00	Q10	Q0
H	L	L	↑	X	a...h	X	a	b	h
H	H	L	↑	H	X	X	H	Q0n	Q6n
H	H	L	↑	L	X	X	L	Q0n	Q6n
H	X	H	↑	X	X	X	Q00	Q10	Q70

NOTES:

H = High Voltage Level

L = Low Voltage Level

X = Don't Care

↑ = Transition from Low to High Level

a...h = The level of steady-state input at inputs D0 thru D7, respectively.

Q00, Q10, Q70 = The level of Q0, Q1, or Q7, respectively, before the indicated steady-state input conditions were established.

Q0n, Q6n = The level of Q0 or Q6, respectively, before the most recent ↑ transition of the clock.

CD74HC166, CD74HCT166

Absolute Maximum Ratings

DC Supply Voltage, V _{CC}	-0.5V to 7V
DC Input Diode Current, I _{IK} For V _I < -0.5V or V _I > V _{CC} + 0.5V	±20mA
DC Output Diode Current, I _{OK} For V _O < -0.5V or V _O > V _{CC} + 0.5V	±20mA
DC Drain Current, per Output, I _O For -0.5V < V _O < V _{CC} + 0.5V	±25mA
DC Output Source or Sink Current per Output Pin, I _O For V _O > -0.5V or V _O < V _{CC} + 0.5V	±25mA
DC V _{CC} or Ground Current, I _{CC} or I _{GND}	±50mA

Thermal Information

Thermal Resistance (Typical, Note 3)	θ _{JA} (°C/W)
PDIP Package	90
SOIC Package	160
Maximum Junction Temperature	150°C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C (SOIC - Lead Tips Only)

Operating Conditions

Temperature Range (T _A)	-55°C to 125°C
Supply Voltage Range, V _{CC}	
HC Types	2V to 6V
HCT Types	4.5V to 5.5V
DC Input or Output Voltage, V _I , V _O	0V to V _{CC}
Input Rise and Fall Time	
2V	1000ns (Max)
4.5V	500ns (Max)
6V	400ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

- 3. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

DC Electrical Specifications

PARAMETER	SYMBOL	TEST CONDITIONS		V _{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V _I (V)	I _O (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES												
High Level Input Voltage	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input Voltage	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I _I	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	µA

CD74HC166, CD74HCT166

DC Electrical Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS		V _{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V _I (V)	I _O (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Quiescent Device Current	I _{CC}	V _{CC} or GND	0	6	-	-	8	-	80	-	160	µA
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I _I	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	µA
Quiescent Device Current	I _{CC}	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	µA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load (Note 4)	ΔI _{CC}	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	µA

NOTE:

4. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
DS, D0-D7	0.2
PE	0.35
CP, CE	0.5
MR	0.2

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at 25°C.

Prerequisite For Switching Specifications

PARAMETER	SYMBOL	V _{CC} (V)	25°C		-40°C TO 85°C		-55°C TO 125°C		UNITS	
			MIN	MAX	MIN	MAX	MIN	MAX		
HC TYPES										
Clock Frequency (Figure 1)	f _{MAX}		2	6	-	5	-	4	-	MHz
			4.5	30	-	25	-	20	-	MHz
			6	35	-	29	-	23	-	MHz

CD74HC166, CD74HCT166

Prerequisite For Switching Specifications (Continued)

PARAMETER	SYMBOL	V _{CC} (V)	25°C		-40°C TO 85°C		-55°C TO 125°C		UNITS
			MIN	MAX	MIN	MAX	MIN	MAX	
MR Pulse Width (Figure 1)	t _w	2	100	-	125	-	150	-	ns
		4.5	20	-	25	-	30	-	ns
		6	17	-	21	-	26	-	ns
Clock Pulse Width (Figure 1)	t _w	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
Set-up Time Data and \overline{CE} to Clock (Figure 5)	t _{SU}	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
Hold Time Data to Clock (Figure 5)	t _H	2	1	-	1	-	1	-	ns
		4.5	1	-	1	-	1	-	ns
		6	1	-	1	-	1	-	ns
Removal Time MR to Clock (Figure 5)	t _{REM}	2	0	-	0	-	0	-	ns
		4.5	0	-	0	-	0	-	ns
		6	0	-	0	-	0	-	ns
Set-up Time \overline{PE} to CP (Figure 5)	t _{SU}	2	145	-	180	-	220	-	ns
		4.5	29	-	36	-	44	-	ns
		6	25	-	31	-	38	-	ns
Hold Time \overline{PE} to CP or \overline{CE} (Figure 5)	t _H	2	0	-	0	-	0	-	ns
		4.5	0	-	0	-	0	-	ns
		6	0	-	0	-	0	-	ns
HCT TYPES									
Clock Frequency (Figure 2)	f _{MAX}	4.5	25	-	20	-	16	-	MHz
MR Pulse Width (Figure 2)	t _w	4.5	35	-	44	-	53	-	ns
Clock Pulse Width (Figure 2)	t _w	4.5	20	-	25	-	30	-	ns
Set-up Time Data and \overline{CE} to Clock (Figure 6)	t _{SU}	4.5	16	-	20	-	24	-	ns
Hold Time Data to Clock (Figure 6)	t _H	4.5	0	-	0	-	0	-	ns
Removal Time MR to Clock (Figure 6)	t _{REM}	4.5	0	-	0	-	0	-	ns
Set-up Time \overline{PE} to CP (Figure 6)	t _{SU}	4.5	30	-	38	-	45	-	ns
Hold Time \overline{PE} to CP or \overline{CE} (Figure 6)	t _H	4.5	0	-	0	-	0	-	ns

Switching Specifications Input t_r, t_f = 6ns

PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	25°C		-40°C TO 85°C		-55°C TO 125°C		UNITS
				TYP	MAX	MAX	MAX	MAX		
HC TYPES										
Propagation Delay, Clock to Output (Figure 3)	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	160	200	240	-	ns	
			4.5	-	32	40	48	-	ns	
		C _L = 15pF	5	13	-	-	-	-	ns	
		C _L = 50pF	6	-	27	34	41	-	ns	

Switching Specifications Input $t_r, t_f = 6\text{ns}$ (Continued)

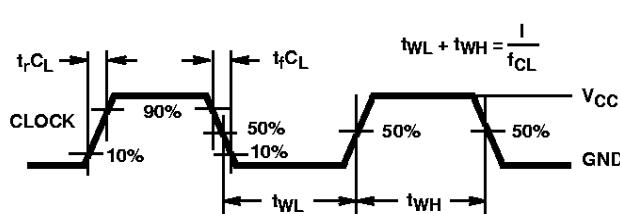
PARAMETER	SYMBOL	TEST CONDITIONS	V_{CC} (V)	25°C		-40°C TO 85°C	-55°C TO 125°C	UNITS
				TYP	MAX	MAX	MAX	
Output Transition Time (Figure 3)	t_{TLH}, t_{THL}	$C_L = 50\text{pF}$	2	-	75	95	110	ns
			4.5	-	15	19	22	ns
			6	-	13	16	19	ns
Propagation Delay MR to Output (Figure 3)	t_{PHL}	$C_L = 50\text{pF}$	2	-	160	200	240	ns
			4.5	-	32	40	48	ns
			6	-	27	34	41	ns
Input Capacitance	C_I	-	-	-	10	10	10	pF
Power Dissipation Capacitance (Notes 5, 6)	C_{PD}	-	5	41	-	-	-	pF
HCT TYPES								
Propagation Delay, Clock to Output (Figure 4)	t_{PLH}, t_{PHL}	$C_L = 50\text{pF}$	4.5	-	40	50	60	ns
Output Transition Time (Figure 4)	t_{TLH}, t_{THL}	$C_L = 50\text{pF}$	4.5	-	15	19	22	ns
Propagation Delay MR to Output (Figure 4)	t_{PHL}	$C_L = 50\text{pF}$	4.5	-	40	50	60	ns
Input Capacitance	C_I	-	-	-	10	10	10	pF

NOTES:

5. C_{PD} is used to determine the dynamic power consumption, per gate.

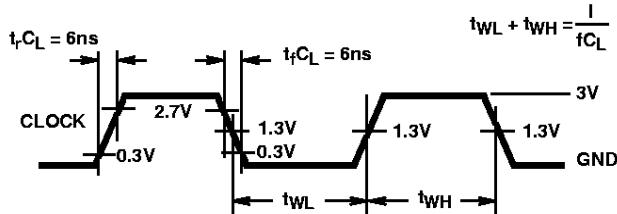
6. $P_D = C_{PD} V_{CC}^2 f_i + \sum (C_L V_{CC}^2 + f_O)$ where f_i = Input Frequency, f_O = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

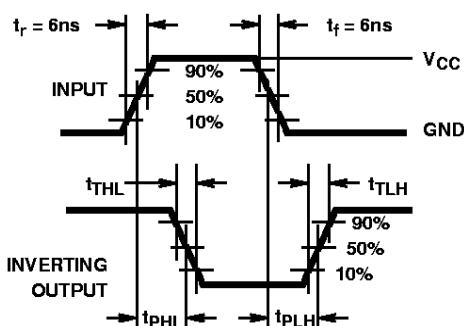


FIGURE 3. HC AND HCU TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

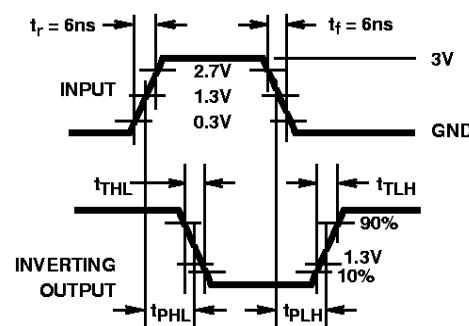


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

Test Circuits and Waveforms (Continued)

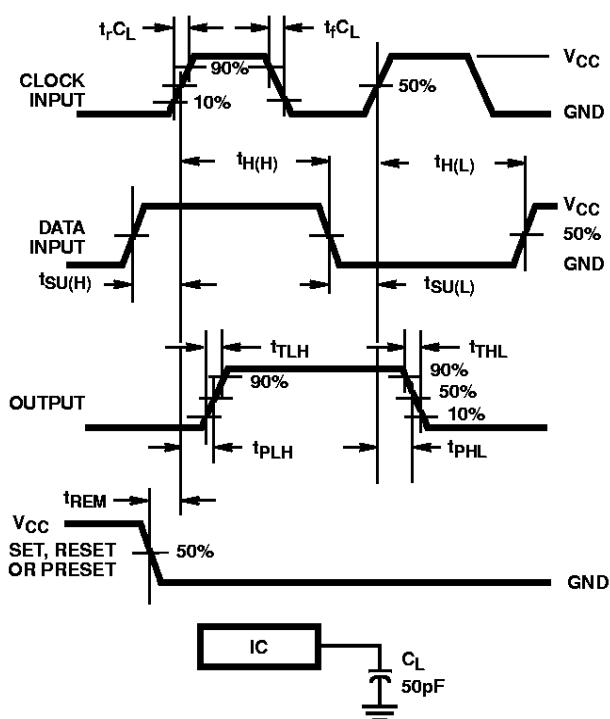


FIGURE 5. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

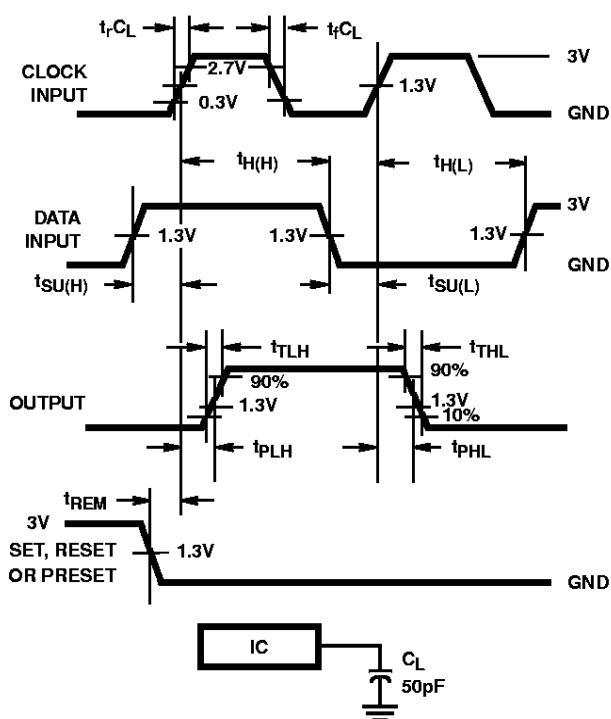


FIGURE 6. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

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